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QUERY CONTROL FORM			RTIS USE ONLY	
Application No. 09 925,102	Prepared by	14	Tracking Number 0588848	9
Examiner-GAU Dana - 2818	Date 1-	29-04	Week Date 011204	1
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JACKET					
a. Serial No.	f. Foreign Priority	k. Print Claim(s)	p. PTO-1449		
b. Applicant(s)	g. Disclaimer	I. Print Fig.	q. PTOL-85b		
c. Continuing Data	h. Microfiche Appendix	m. Searched Column	r. Abstract		
d. PCT	i. Title	n. PTO-270/328	s. Sheets/Figs		
e. Domestic Priority	j. Claims Allowed	o. PTO-892	t. Other		

SPECIFICATION	MESSAGE
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g. Brief Description	
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Sheet 2 of 2

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	(Use several sheets if necessary)				Jack H. Yuan et al.				
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QUERY CONTROL FORM		RTIS USE ONLY
Application No. 09 950, 959	Prepared by N.H.	Tracking Number 05884677
Examiner-GAU Le- 2858	Date 1-29-0'	Week Date 0105 04
	No. of queries 1	IFW

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k. Other	
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PAGE 1 OF 1

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2013/01/20		U.S. PAT	ENT DOCUMENT	rs					
Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing I	Date opriate		
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citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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